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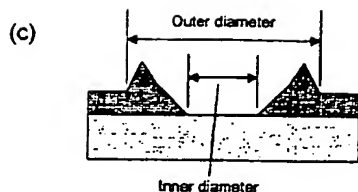
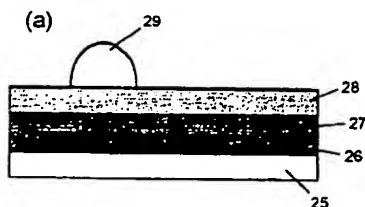
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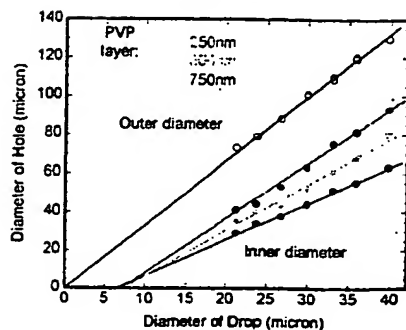
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- (71) Applicant (for all designated States except US): PLASTIC LOGIC LIMITED [GB/GB]; Sheraton House, Castle Park, Cambridge CB3 0AX (GB).
- (72) Inventors; and
(75) Inventors/Applicants (for US only): SIRRINGHAUS, Henning [DE/GB]; Churchill College, Cambridge CB3 0DS (GB). FRIEND, Richard, Henry [GB/GB]; 37 Barton Road, Cambridge CB3 9LG (GB). KAWASE, Takeo [JP/GB]; 18 Eachard Road, Cambridge CB3 6HY (GB).
- (74) Agents: SLINGSBY, Philip, Roy et al.; Page White & Farrer, 54 Doughty Street, London WC1N 2LS (GB).
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[Continued on next page]

(54) Title: FORMING INTERCONNECTS



(57) Abstract: A method for forming an electronic device, comprising: forming a first conductive or semiconductive layer; forming a sequence of at least one insulating layer and at least one semiconducting layer over the first conductive or semiconductive layer; locally depositing solvents at a localised region of the insulating layer so as to dissolve the sequence of insulating and semiconducting layers in the region to leave a void extending through the sequence of layers; and depositing conductive or semiconductive material in the void.



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patent (AM, AZ, BY, KG, KZ, MD, RU, TJ, TM), European
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IT, LU, MC, NL, PT, SE, TR), OAPI patent (BF, BJ, CF,
CG, CI, CM, GA, GN, GW, ML, MR, NE, SN, TD, TG).

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For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

PC1/GB 00/04940

A. CLASSIFICATION OF SUBJECT MATTER
IPC 7 H01L51/40 H01L21/311

IPC 7 HOLL

INSPEC, EPO-Internal

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
X	WO 99 10939 A (KONINKL PHILIPS ELECTRONICS NV ;PHILIPS AB (SE)) 4 March 1999 (1999-03-04) the whole document ---	44-48
X	WO 99 12398 A (CAMBRIDGE DISPLAY TECH ;FRIEND RICHARD HENRY (GB)) 11 March 1999 (1999-03-11) the whole document ---	44-48
X	EP 0 933 814 A (IMEC INTER UNI MICRO ELECTR) 4 August 1999 (1999-08-04) the whole document ---	49
A	US 4 140 572 A (STEIN LEONARD) 20 February 1979 (1979-02-20) the whole document ---	1,4

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☒ Patent family members are listed in annex.

*& document member of the same patent family

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INTERNATIONAL SEARCH REPORT

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C.(Continuation) DOCUMENTS CONSIDERED TO BE RELEVANT

Category *	Citation of document, with indication, where appropriate, of the relevant passages	Relevant to claim No.
A	EP 0 923 112 A (CLARIANT INT LTD) 16 June 1999 (1999-06-16) the whole document ---	1,4
A	EP 0 930 641 A (SEIKO EPSON CORP) 21 July 1999 (1999-07-21) the whole document -----	1

INTERNATIONAL SEARCH REPORT

International application No.
PCT/GB 00/04940

Box I Observations where certain claims were found unsearchable (Continuation of item 1 of first sheet)

This International Search Report has not been established in respect of certain claims under Article 17(2)(a) for the following reasons:

1. ☐ Claims Nos.:
because they relate to subject matter not required to be searched by this Authority, namely:

2. ☐ Claims Nos.:
because they relate to parts of the International Application that do not comply with the prescribed requirements to such an extent that no meaningful International Search can be carried out, specifically:

3. ☐ Claims Nos.:
because they are dependent claims and are not drafted in accordance with the second and third sentences of Rule 6.4(a).

Box II Observations where unity of invention is lacking (Continuation of item 2 of first sheet)

This International Searching Authority found multiple inventions in this international application, as follows:

see additional sheet

1. ☐ As all required additional search fees were timely paid by the applicant, this International Search Report covers all searchable claims.

2. ☐ As all searchable claims could be searched without effort justifying an additional fee, this Authority did not invite payment of any additional fee.

3. ☐ As only some of the required additional search fees were timely paid by the applicant, this International Search Report covers only those claims for which fees were paid, specifically claims Nos.:

4. ☒ No required additional search fees were timely paid by the applicant. Consequently, this International Search Report is restricted to the invention first mentioned in the claims; it is covered by claims Nos.:

1-38, 44-49

Remark on Protest

- ☐ The additional search fees were accompanied by the applicant's protest.
- ☐ No protest accompanied the payment of additional search fees.

FURTHER INFORMATION CONTINUED FROM PCT/ISA/ 210

This International Searching Authority found multiple (groups of) inventions in this international application, as follows:

1. Claims: 1-38,44-49

Patterning of organic insulating layers by selective etching

The prior Art describes a field effect transistor substantially consisting of organic materials.

The new features mentioned in claims 1-38 are contact holes, made in organic dielectric layers by wet etching using an ink-jet printing system to locally supply the etch liquid.

From this we can formulate an objective problem of making contact holes in organic dielectric layers by wet etching using an ink-jet printing system to locally supply the etch liquid.

The special technical features, as defined in Rule 13(2) PCT, are contact holes, made in organic dielectric layers by wet etching using an ink-jet printing system to locally supply the etch liquid.

2. Claims: 39-43

Selective doping of organic insulating layers

The prior Art describes a field effect transistor substantially consisting of organic materials.

The new features mentioned in claims 1-38 are conductive (interconnection) patterns made by selective doping organic insulating layers to make them conductive. The dopants are applied using an ink-jet printing system.

From this we can formulate an objective problem of making conductive patterns made by selective doping organic insulating layers to make them conductive, applying the dopants are using an ink-jet printing system.

The special technical features, as defined in Rule 13(2) PCT, are conductive (interconnection) patterns made by selective doping organic insulating layers to make them conductive. The dopants are applied using an ink-jet printing system.

INTERNATIONAL SEARCH REPORT

Information on patent family members

International Application No

PCT/GB 00/04940

Patent document cited in search report	Publication date	Patent family member(s)	Publication date
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